

P-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
- 20	0.195 at $V_{GS} = - 4.5$ V	- 0.84
	0.260 at $V_{GS} = - 2.5$ V	- 0.73
	0.350 at $V_{GS} = - 1.8$ V	- 0.64

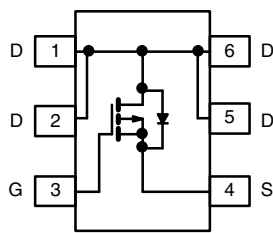
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Low Threshold
- Smallest LITTLE FOOT[®] Package: 1.6 mm x 1.6 mm
- Low 0.6 mm Profile
- Compliant to RoHS Directive 2002/95/EC



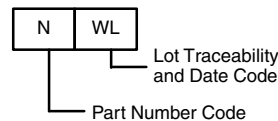
RoHS
COMPLIANT
HALOGEN
FREE

SC-89 (6-LEADS)



Top View

Marking Code



APPLICATIONS

- Cell Phones and Pagers
- Load Switch
- Battery Operated Systems

Ordering Information: Si1037X-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)					
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage	V_{DS}	- 20		V	
Gate-Source Voltage	V_{GS}	± 8			
Continuous Drain Current ($T_J = 150$ °C) ^a	I_D	$T_A = 25$ °C	- 0.84	- 0.77	A
		$T_A = 70$ °C	- 0.68	- 0.62	
Pulsed Drain Current	I_{DM}	- 4			
Continuous Diode Current (Diode Conduction) ^a	I_S	- 0.18	- 0.14		
Maximum Power Dissipation ^a	P_D	$T_A = 25$ °C	0.21	0.17	W
		$T_A = 70$ °C	0.13	0.10	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	500	600	°C/W	
		600	720		

Notes:

a. Surface mounted on 1" x 1" FR4 board with minimum copper.



SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 0.45			V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1	μA
		V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 70 °C			- 5	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 4			A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 0.77 A		0.160	0.195	Ω
		V _{GS} = - 2.5 V, I _D = - 0.67 A		0.212	0.260	
		V _{GS} = - 1.8 V, I _D = - 0.2 A		0.290	0.350	
Forward Transconductance ^a	g _{fs}	V _{DS} = - 10 V, I _D = - 0.77 A		3.1		S
Diode Forward Voltage ^a	V _{SD}	I _S = - 0.14 A, V _{GS} = 0 V		- 0.78	- 1.2	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 0.77 A		3.5	5.5	nC
Gate-Source Charge	Q _{gs}			0.65		
Gate-Drain Charge	Q _{gd}			0.60		
Turn-On Delay Time	t _{d(on)}	V _{DD} = - 10 V, R _L = 20 Ω I _D ≅ - 0.5 A, V _{GEN} = - 4.5 V, R _G = 6 Ω		10	20	ns
Rise Time	t _r			15	30	
Turn-Off Delay Time	t _{d(off)}			30	60	
Fall Time	t _f			10	20	
Source-Drain Reverse Recovery Time	t _{rr}		I _F = - 0.14 A, di/dt = 100 A/μs		20	

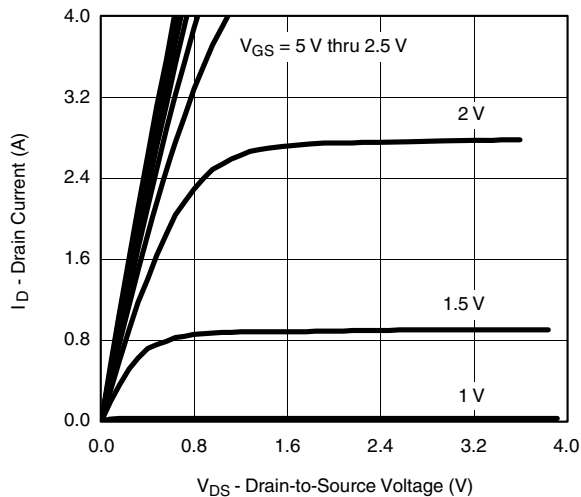
Notes:

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.

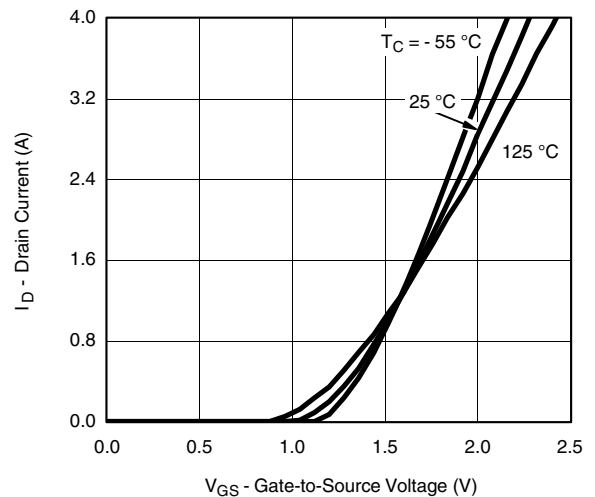
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

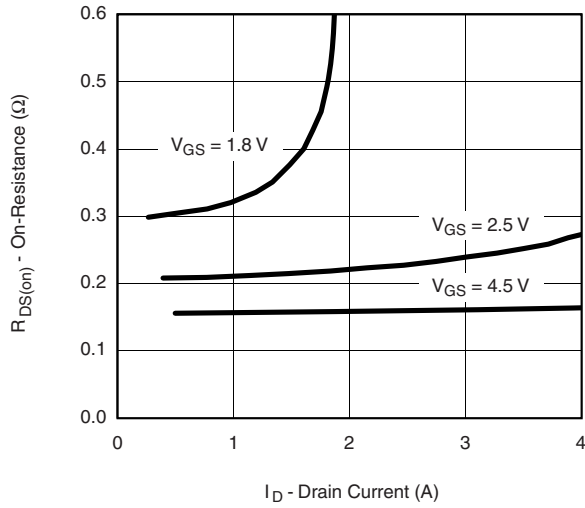


Output Characteristics

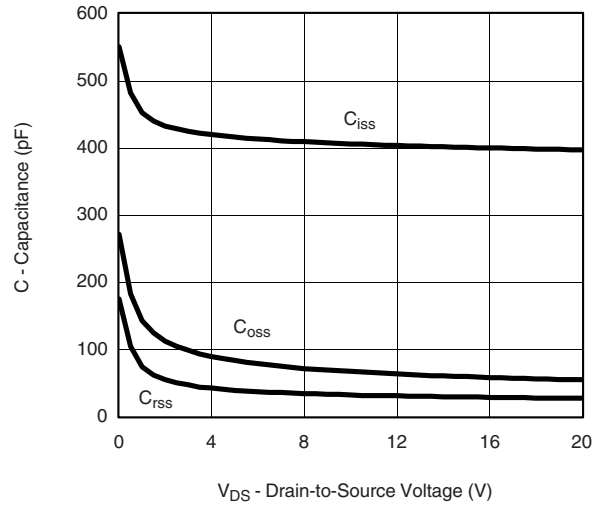


Transfer Characteristics

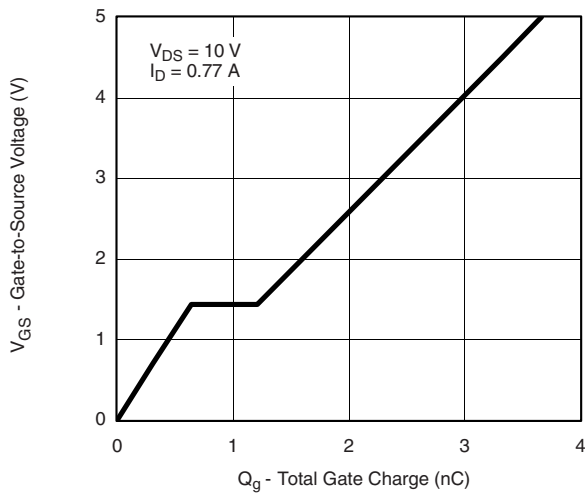
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



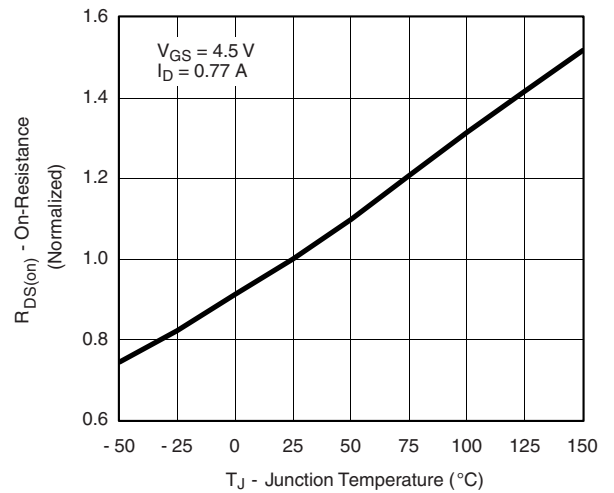
On-Resistance vs. Drain Current



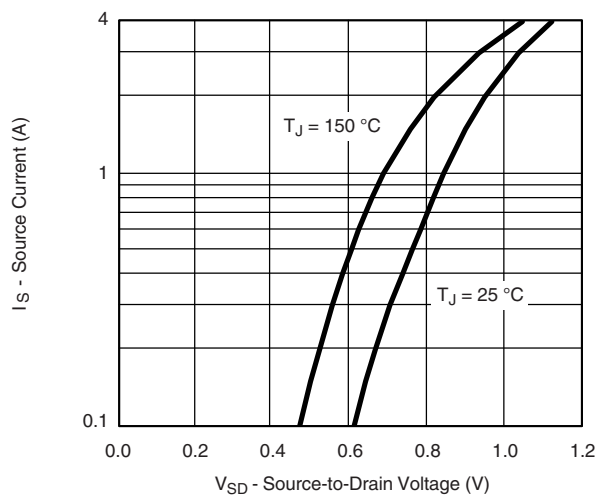
Capacitance



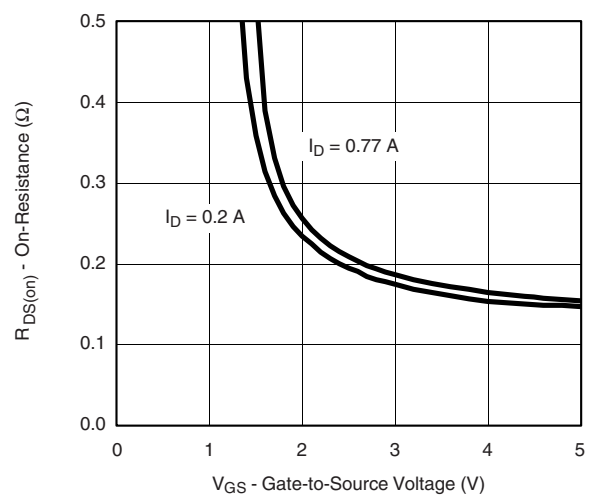
Gate Charge



On-Resistance vs. Junction Temperature

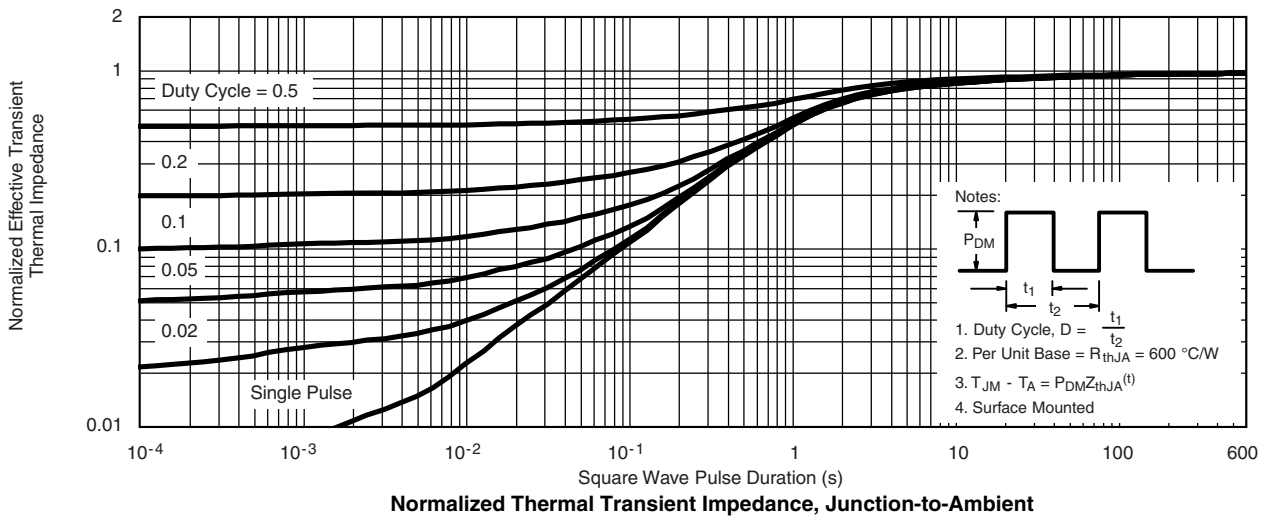
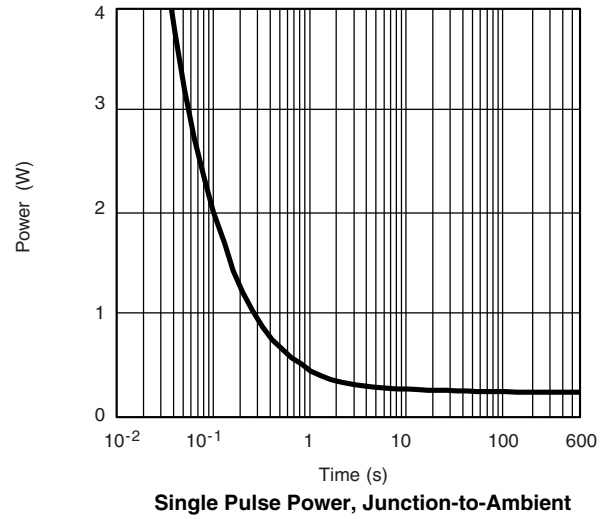
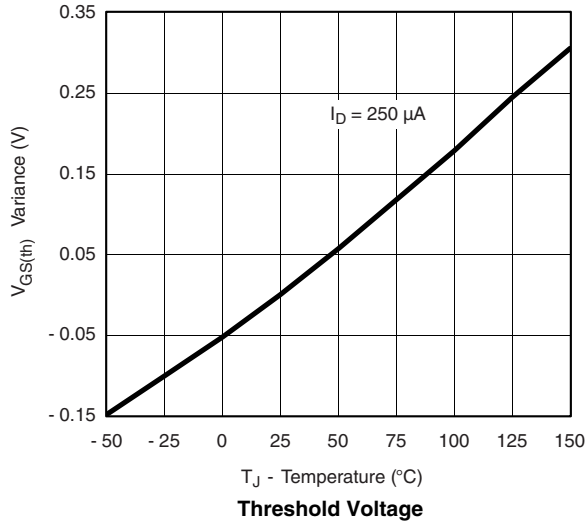


Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



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